

## CSD17585F5 30-V N-Channel FemtoFET™ MOSFET

### 1 Features

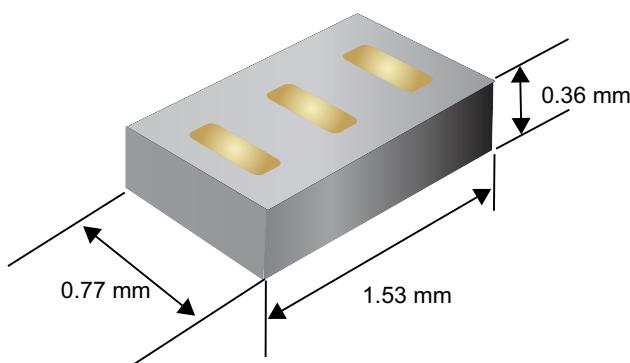
- Low-on resistance
- Ultra-low  $Q_g$  and  $Q_{gd}$
- Ultra-small footprint
  - 1.53 mm × 0.77 mm
- Low profile
  - 0.36-mm height
- Integrated ESD protection diode
  - Rated > 4-kV HBM
  - Rated > 2-kV CDM
- Lead and halogen free
- RoHS compliant

### 2 Applications

- Optimized for industrial load switch applications
- Optimized for general purpose switching applications

### 3 Description

This 30-V, 22-mΩ, N-Channel FemtoFET™ MOSFET technology is designed and optimized to minimize the footprint in many handheld and mobile applications. This technology is capable of replacing standard small signal MOSFETs while providing a significant reduction in footprint size.



**Figure 3-1. Typical Part Dimensions**

### Product Summary

$T_A = 25^\circ\text{C}$		TYPICAL VALUE	UNIT
$V_{DS}$	Drain-to-Source Voltage	30	V
$Q_g$	Gate Charge Total (4.5 V)	1.9	nC
$Q_{gd}$	Gate Charge Gate-to-Drain	0.39	nC
$R_{DS(on)}$	Drain-to-Source On Resistance	$V_{GS} = 4.5 \text{ V}$ $V_{GS} = 10 \text{ V}$	26 22 mΩ
$V_{GS(th)}$	Threshold Voltage	1.3	V

### Device Information

DEVICE <sup>(1)</sup>	QTY	MEDIA	PACKAGE	SHIP
CSD17585F5	3000		Femto 1.53-mm × 0.77-mm	
CSD17585F5T	250	7-Inch Reel	SMD Lead Less	Tape and Reel

(1) For all available packages, see the orderable addendum at the end of the data sheet.

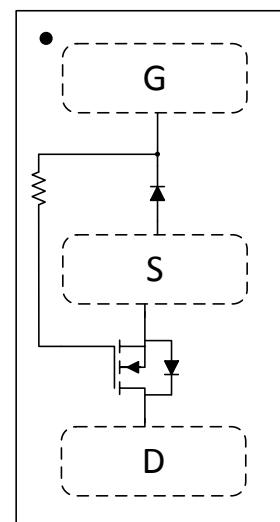
### Absolute Maximum Ratings

$T_A = 25^\circ\text{C}$		VALUE	UNIT
$V_{DS}$	Drain-to-Source Voltage	30	V
$V_{GS}$	Gate-to-Source Voltage	+20	V
$I_D$	Continuous Drain Current <sup>(1)</sup>	3.6	A
	Continuous Drain Current <sup>(2)</sup>	5.9	
$I_{DM}$	Pulsed Drain Current <sup>(1) (3)</sup>	34	A
$P_D$	Power Dissipation <sup>(1)</sup>	0.5	W
	Power Dissipation <sup>(2)</sup>	1.4	
$V_{(ESD)}$	Human-Body Model (HBM)	4	kV
	Charged-Device Model (CDM)	2	
$T_J$ , $T_{stg}$	Operating Junction, Storage Temperature	-55 to 150	°C

(1) Min Cu, typical  $R_{\theta JA} = 245^\circ\text{C}/\text{W}$ .

(2) Max Cu, typical  $R_{\theta JA} = 90^\circ\text{C}/\text{W}$ .

(3) Pulse duration ≤ 100 µs, duty cycle ≤ 1%.



**Figure 3-2. Top View**



An IMPORTANT NOTICE at the end of this data sheet addresses availability, warranty, changes, use in safety-critical applications, intellectual property matters and other important disclaimers. PRODUCTION DATA.

## Table of Contents

<b>1 Features.....</b>	<b>1</b>	<b>6 Device and Documentation Support.....</b>	<b>7</b>
<b>2 Applications.....</b>	<b>1</b>	<b>6.1 Receiving Notification of Documentation Updates.....</b>	<b>7</b>
<b>3 Description.....</b>	<b>1</b>	<b>6.2 Trademarks.....</b>	<b>7</b>
<b>4 Revision History.....</b>	<b>2</b>	<b>7 Mechanical, Packaging, and Orderable Information.....</b>	<b>8</b>
<b>5 Specifications.....</b>	<b>3</b>	<b>7.1 Mechanical Dimensions.....</b>	<b>8</b>
5.1 Electrical Characteristics.....	3	<b>7.2 Recommended Minimum PCB Layout.....</b>	<b>9</b>
5.2 Thermal Information.....	3	<b>7.3 Recommended Stencil Pattern.....</b>	<b>9</b>
5.3 Typical MOSFET Characteristics.....	4		

## 4 Revision History

NOTE: Page numbers for previous revisions may differ from page numbers in the current version.

<b>Changes from Revision B (February 2022) to Revision C (June 2022)</b>	<b>Page</b>
• Restored front page key graphic to match SLPS610A.....	1
• Restored layout of images to match SLPS610A.....	4

<b>Changes from Revision A (December 2016) to Revision B (February 2022)</b>	<b>Page</b>
• Changed ultra-low profile bullet from 0.35 mm to 0.36 mm in height.....	1
• Updated ultra-low profile image height from 0.35 mm to 0.36 mm.....	1
• Changed ultra-low profile image height from 0.35 mm to 0.36 mm.....	8
• Added FemtoFET Surface Mount Guide note.....	9

<b>Changes from Revision * (October 2016) to Revision A (December 2016)</b>	<b>Page</b>
• Changed <a href="#">Figure 5-2</a> in the <i>Typical MOSFET Characteristics</i> section.....	4
• Added <a href="#">Table 7-1</a> in the <i>Mechanical Dimensions</i> section.....	8

## 5 Specifications

### 5.1 Electrical Characteristics

$T_A = 25^\circ\text{C}$  (unless otherwise stated)

PARAMETER	TEST CONDITIONS	MIN	TYP	MAX	UNIT
<b>STATIC CHARACTERISTICS</b>					
$\text{BV}_{\text{DSS}}$	Drain-to-source voltage $V_{\text{GS}} = 0 \text{ V}, I_{\text{DS}} = 250 \mu\text{A}$	30			V
$I_{\text{DSS}}$	Drain-to-source leakage current $V_{\text{GS}} = 0 \text{ V}, V_{\text{DS}} = 24 \text{ V}$		100		nA
$I_{\text{GSS}}$	Gate-to-source leakage current $V_{\text{DS}} = 0 \text{ V}, V_{\text{GS}} = 20 \text{ V}$		50		nA
$V_{\text{GS}(\text{th})}$	Gate-to-source threshold voltage $V_{\text{DS}} = V_{\text{GS}}, I_{\text{DS}} = 250 \mu\text{A}$	0.9	1.3	1.7	V
$R_{\text{DS}(\text{on})}$	Drain-to-source on resistance $V_{\text{GS}} = 4.5 \text{ V}, I_{\text{DS}} = 0.9 \text{ A}$	26	33		$\text{m}\Omega$
	$V_{\text{GS}} = 10 \text{ V}, I_{\text{DS}} = 0.9 \text{ A}$	22	27		
$g_{\text{fs}}$	Transconductance $V_{\text{DS}} = 3 \text{ V}, I_{\text{DS}} = 0.9 \text{ A}$	7			S
<b>DYNAMIC CHARACTERISTICS</b>					
$C_{\text{iss}}$	Input capacitance $V_{\text{GS}} = 0 \text{ V}, V_{\text{DS}} = 15 \text{ V}, f = 1 \text{ MHz}$	292	380		pF
$C_{\text{oss}}$	Output capacitance	166	215		pF
$C_{\text{rss}}$	Reverse transfer capacitance	5.7	7.4		pF
$R_G$	Series gate resistance	34			$\Omega$
$Q_g$	Gate charge total (4.5 V)	1.9	2.4		nC
$Q_g$	Gate charge total (10 V)	3.9	5.1		nC
$Q_{\text{gd}}$	Gate charge gate-to-drain $V_{\text{DS}} = 15 \text{ V}, I_{\text{DS}} = 0.9 \text{ A}$	0.39			nC
$Q_{\text{gs}}$	Gate charge gate-to-source	0.53			nC
$Q_{\text{g}(\text{th})}$	Gate charge at $V_{\text{th}}$	0.42			nC
$Q_{\text{oss}}$	Output charge $V_{\text{DS}} = 15 \text{ V}, V_{\text{GS}} = 0 \text{ V}$	4.1			nC
$t_{\text{d}(\text{on})}$	Turnon delay time	4			ns
$t_r$	Rise time $V_{\text{DS}} = 15 \text{ V}, V_{\text{GS}} = 4.5 \text{ V}, I_{\text{DS}} = 0.9 \text{ A}, R_G = 2 \Omega$	4			ns
$t_{\text{d}(\text{off})}$	Turnoff delay time	31			ns
$t_f$	Fall time	11			ns
<b>DIODE CHARACTERISTICS</b>					
$V_{\text{SD}}$	Diode forward voltage $I_{\text{SD}} = 0.9 \text{ A}, V_{\text{GS}} = 0 \text{ V}$	0.74	1.0		V

### 5.2 Thermal Information

$T_A = 25^\circ\text{C}$  (unless otherwise stated)

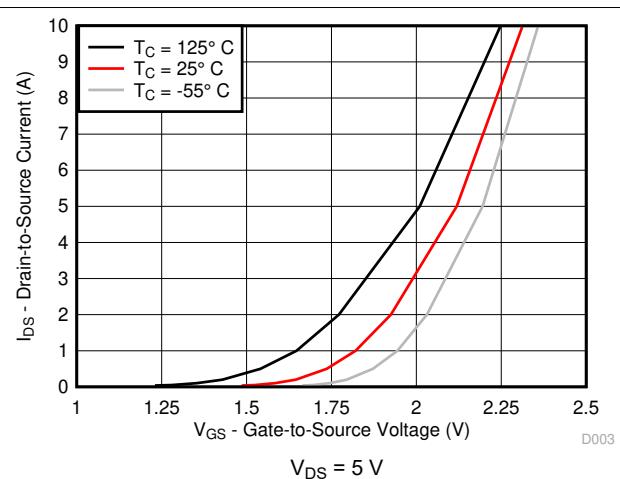
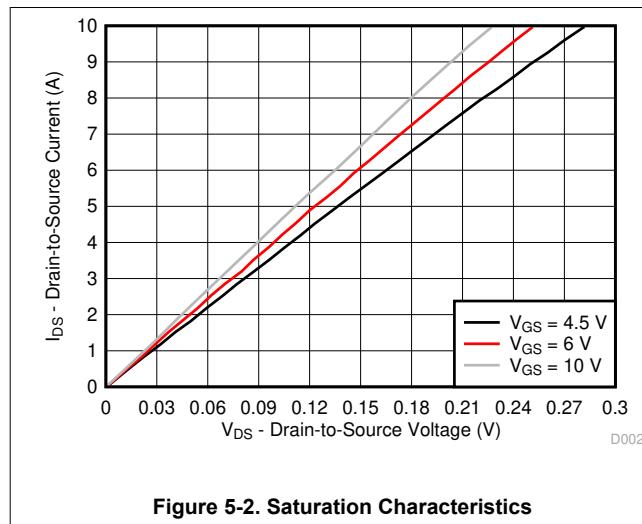
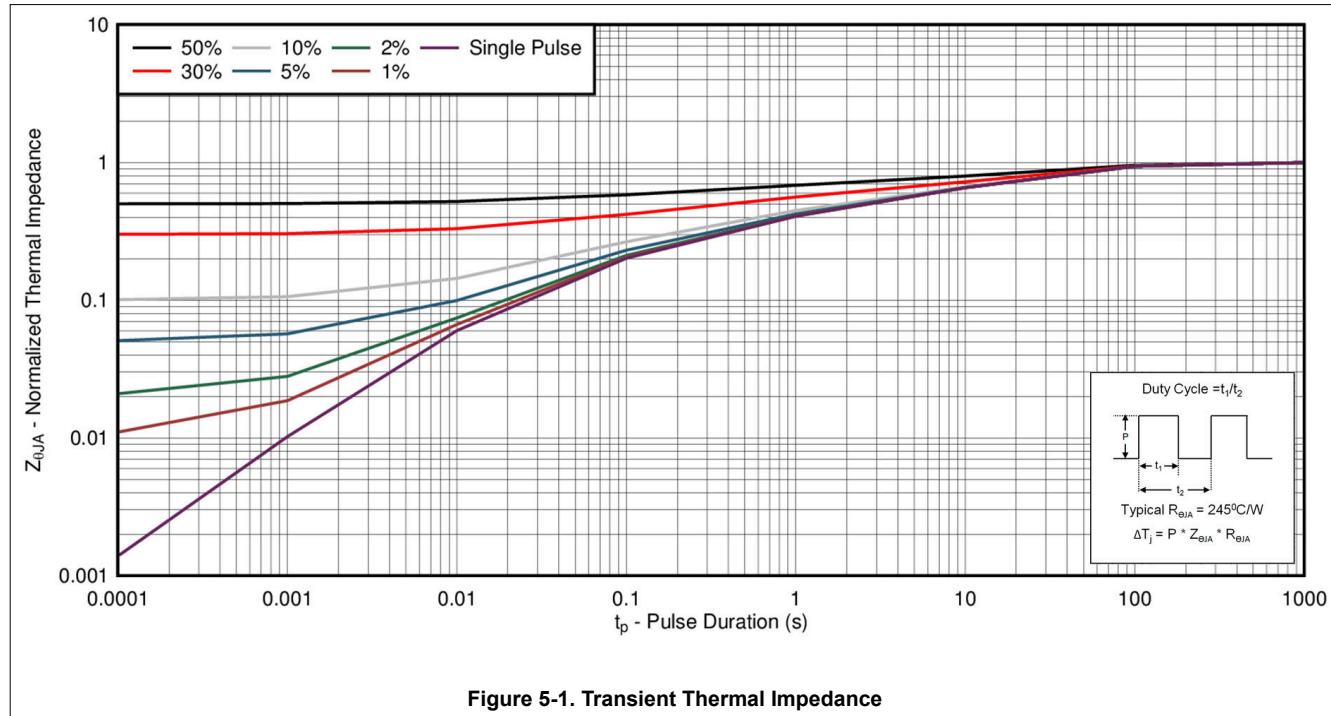
THERMAL METRIC		MIN	TYP	MAX	UNIT
$R_{\theta\text{JA}}$	Junction-to-ambient thermal resistance <sup>(1)</sup>	90			$^{\circ}\text{C}/\text{W}$
	Junction-to-ambient thermal resistance <sup>(2)</sup>	245			

(1) Device mounted on FR4 material with 1-in<sup>2</sup> (6.45-cm<sup>2</sup>), 2-oz (0.071-mm) thick Cu.

(2) Device mounted on FR4 material with minimum Cu mounting area.

## 5.3 Typical MOSFET Characteristics

$T_A = 25^\circ\text{C}$  (unless otherwise stated)



### 5.3 Typical MOSFET Characteristics (continued)

$T_A = 25^\circ\text{C}$  (unless otherwise stated)

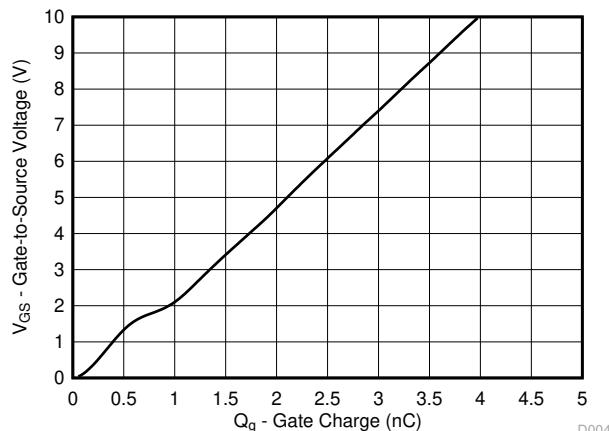


Figure 5-4. Gate Charge

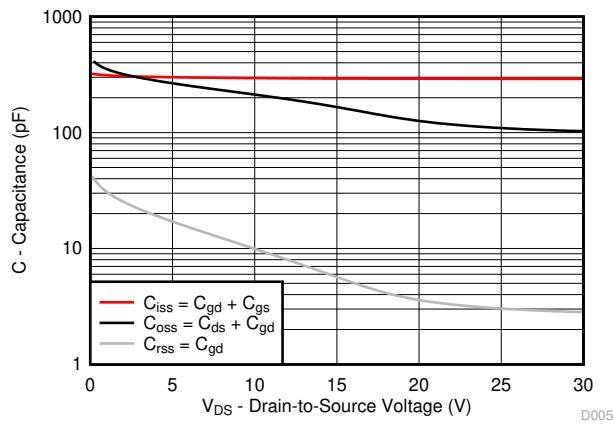


Figure 5-5. Capacitance

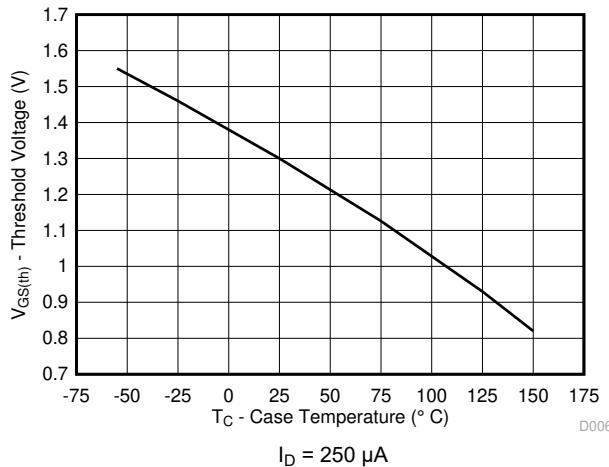


Figure 5-6. Threshold Voltage vs Temperature

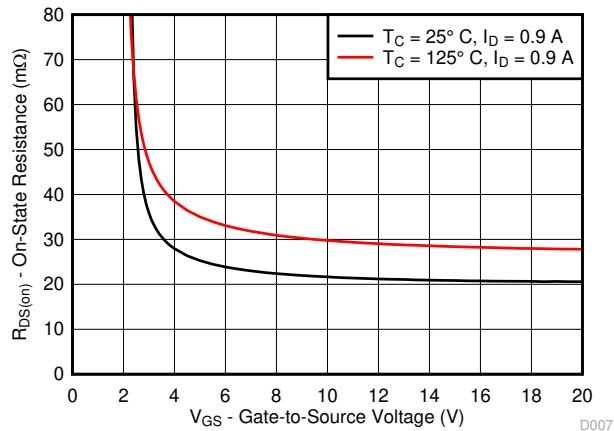


Figure 5-7. On-State Resistance vs Gate-to-Source Voltage

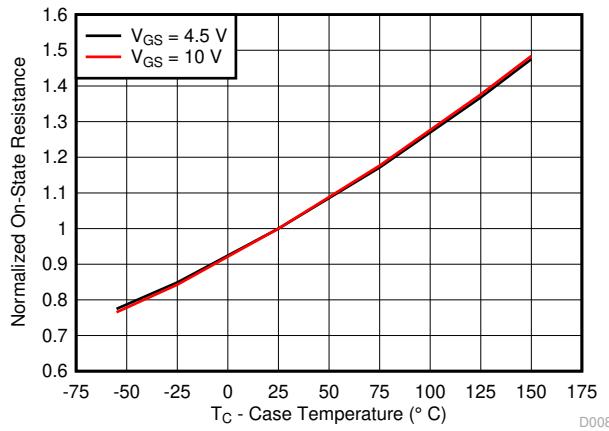


Figure 5-8. Normalized On-State Resistance vs Temperature

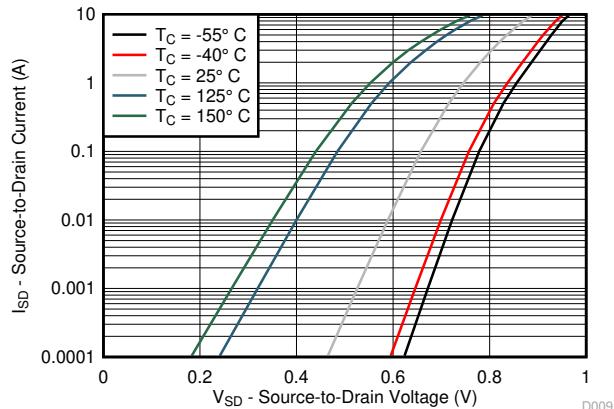
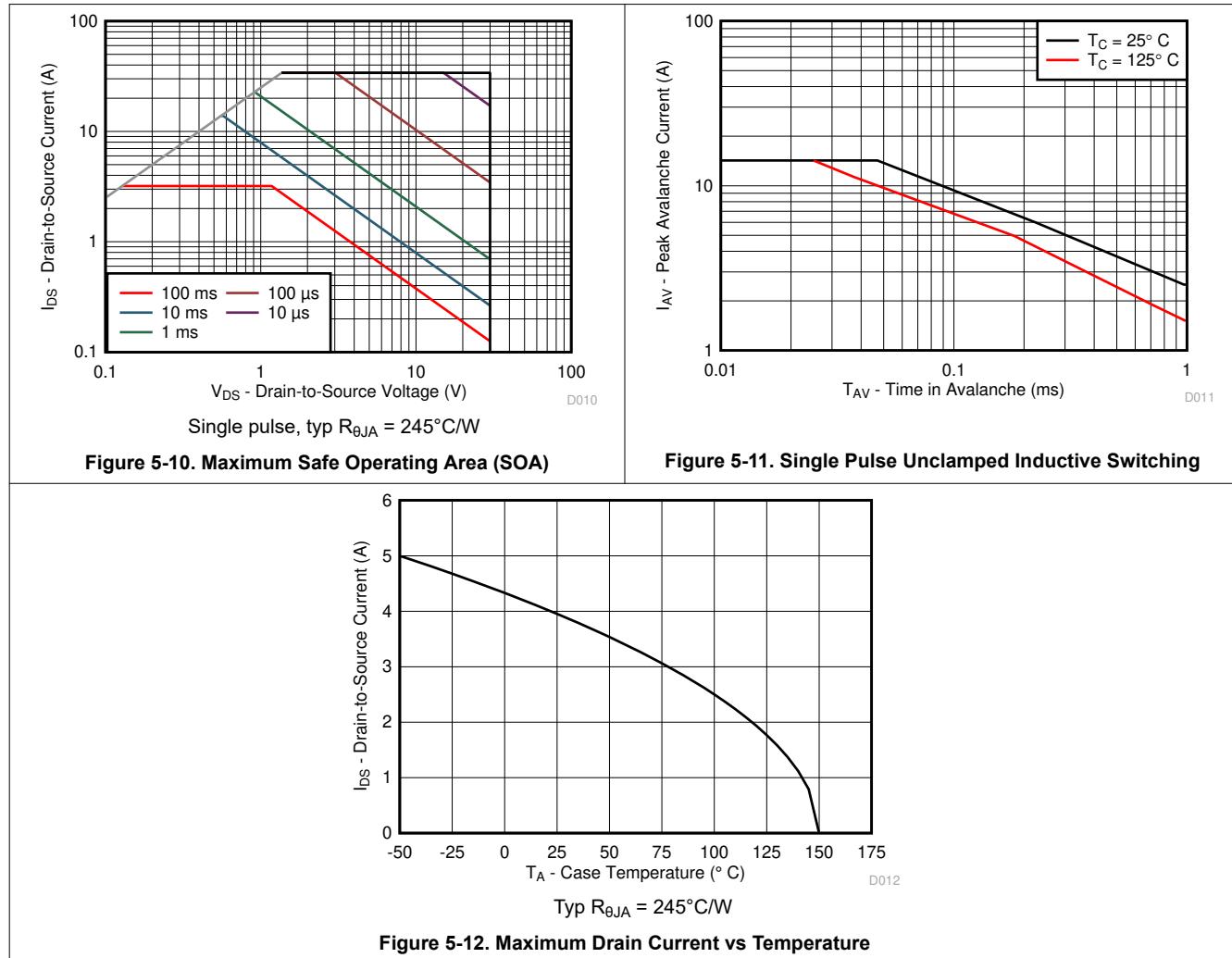


Figure 5-9. Typical Diode Forward Voltage

### 5.3 Typical MOSFET Characteristics (continued)

$T_A = 25^\circ\text{C}$  (unless otherwise stated)



## 6 Device and Documentation Support

### 6.1 Receiving Notification of Documentation Updates

To receive notification of documentation updates, navigate to the device product folder on [ti.com](http://ti.com). In the upper right corner, click on *Alert me* to register and receive a weekly digest of any product information that has changed. For change details, review the revision history included in any revised document.

### 6.2 Trademarks

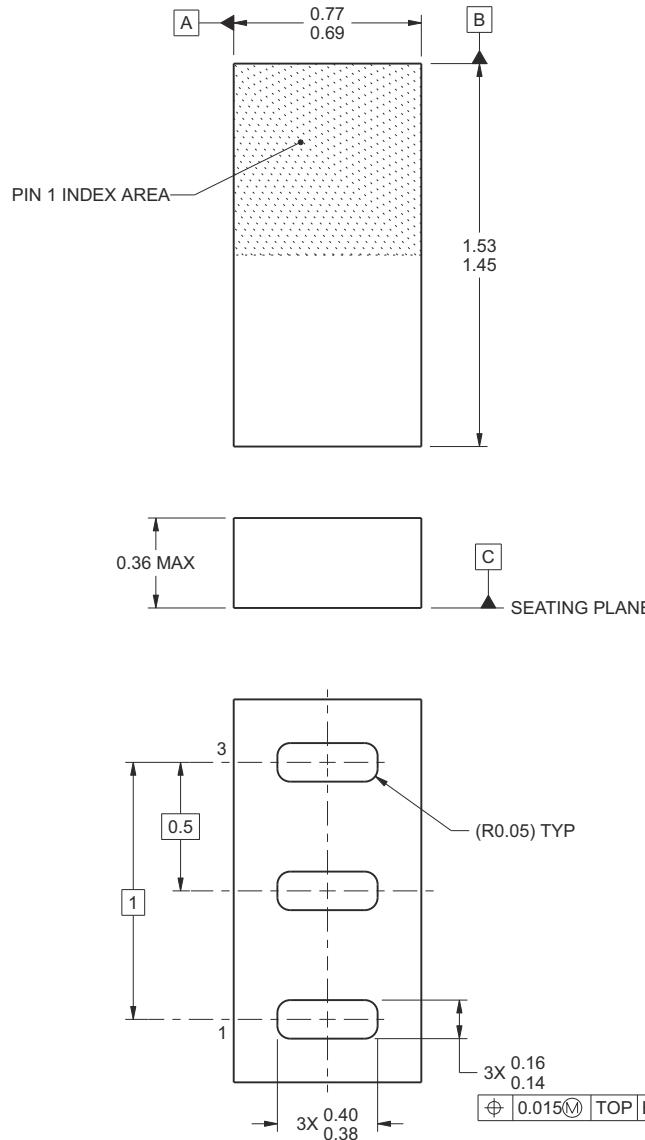
FemtoFET™ is a trademark of Texas Instruments.

All trademarks are the property of their respective owners.

## 7 Mechanical, Packaging, and Orderable Information

The following pages include mechanical, packaging, and orderable information. This information is the most current data available for the designated devices. This data is subject to change without notice and revision of this document. For browser-based versions of this data sheet, refer to the left-hand navigation.

### 7.1 Mechanical Dimensions



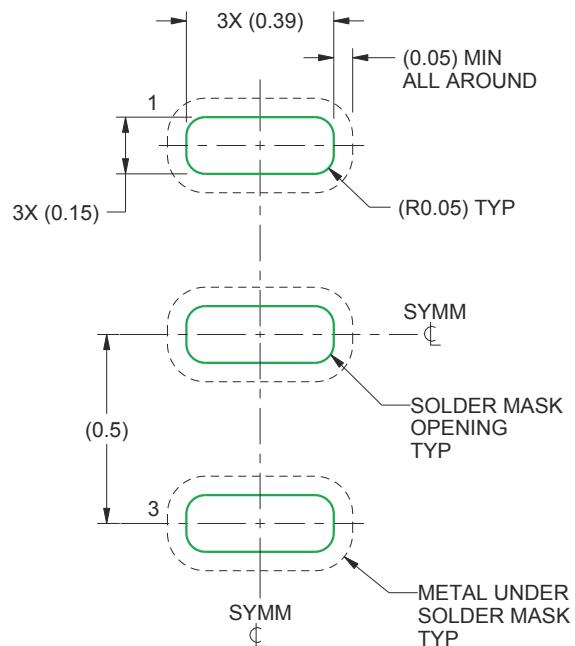
4222132/A 06/2015

- A. All linear dimensions are in millimeters (dimensions and tolerancing per AME T14.5M-1994).
- B. This drawing is subject to change without notice.
- C. This package is a PB-free solder land design.

**Table 7-1. Pin Configuration**

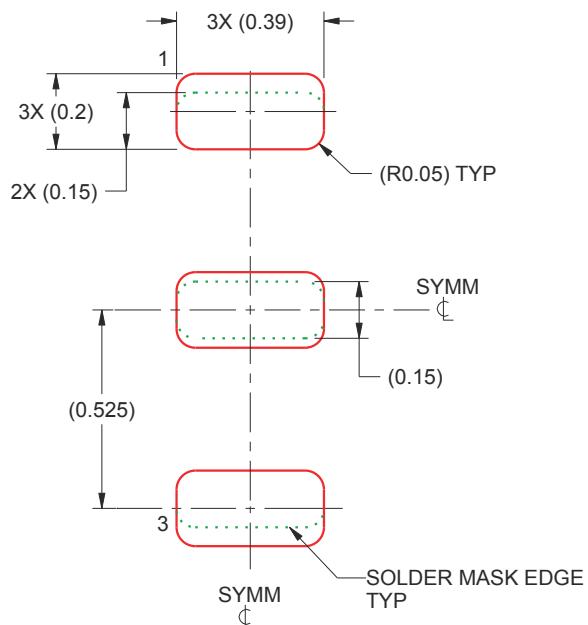
POSITION	DESIGNATION
Pin 1	Gate
Pin 2	Source
Pin 3	Drain

## 7.2 Recommended Minimum PCB Layout



- A. All dimensions are in millimeters.
- B. For more information, see *FemtoFET Surface Mount Guide* (SLRA003D).

## 7.3 Recommended Stencil Pattern



- A. All dimensions are in millimeters.

**PACKAGING INFORMATION**

Orderable part number	Status (1)	Material type (2)	Package   Pins	Package qty   Carrier	RoHS (3)	Lead finish/ Ball material (4)	MSL rating/ Peak reflow (5)	Op temp (°C)	Part marking (6)
CSD17585F5	Active	Production	PICOSTAR (YJK)   3	3000   LARGE T&R	Yes	NIAU	Level-1-260C-UNLIM	-55 to 150	4U
CSD17585F5.B	Active	Production	PICOSTAR (YJK)   3	3000   LARGE T&R	Yes	NIAU	Level-1-260C-UNLIM	-55 to 150	4U
CSD17585F5T	Active	Production	PICOSTAR (YJK)   3	250   SMALL T&R	Yes	NIAU	Level-1-260C-UNLIM	-55 to 150	4U
CSD17585F5T.B	Active	Production	PICOSTAR (YJK)   3	250   SMALL T&R	Yes	NIAU	Level-1-260C-UNLIM	-55 to 150	4U

<sup>(1)</sup> **Status:** For more details on status, see our [product life cycle](#).

<sup>(2)</sup> **Material type:** When designated, preproduction parts are prototypes/experimental devices, and are not yet approved or released for full production. Testing and final process, including without limitation quality assurance, reliability performance testing, and/or process qualification, may not yet be complete, and this item is subject to further changes or possible discontinuation. If available for ordering, purchases will be subject to an additional waiver at checkout, and are intended for early internal evaluation purposes only. These items are sold without warranties of any kind.

<sup>(3)</sup> **RoHS values:** Yes, No, RoHS Exempt. See the [TI RoHS Statement](#) for additional information and value definition.

<sup>(4)</sup> **Lead finish/Ball material:** Parts may have multiple material finish options. Finish options are separated by a vertical ruled line. Lead finish/Ball material values may wrap to two lines if the finish value exceeds the maximum column width.

<sup>(5)</sup> **MSL rating/Peak reflow:** The moisture sensitivity level ratings and peak solder (reflow) temperatures. In the event that a part has multiple moisture sensitivity ratings, only the lowest level per JEDEC standards is shown. Refer to the shipping label for the actual reflow temperature that will be used to mount the part to the printed circuit board.

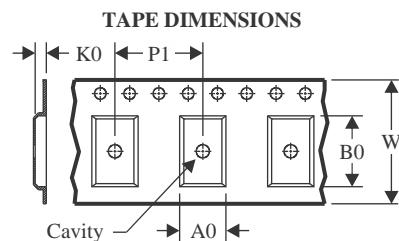
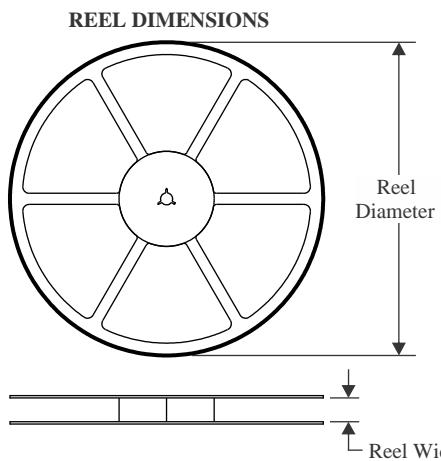
<sup>(6)</sup> **Part marking:** There may be an additional marking, which relates to the logo, the lot trace code information, or the environmental category of the part.

Multiple part markings will be inside parentheses. Only one part marking contained in parentheses and separated by a "~" will appear on a part. If a line is indented then it is a continuation of the previous line and the two combined represent the entire part marking for that device.

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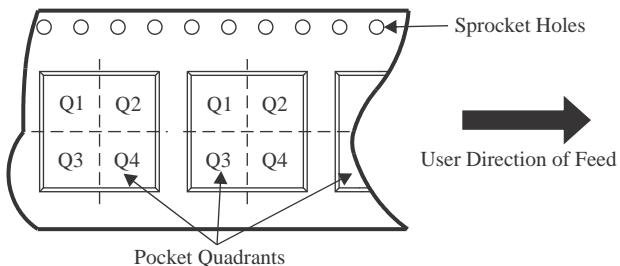
In no event shall TI's liability arising out of such information exceed the total purchase price of the TI part(s) at issue in this document sold by TI to Customer on an annual basis.

## TAPE AND REEL INFORMATION



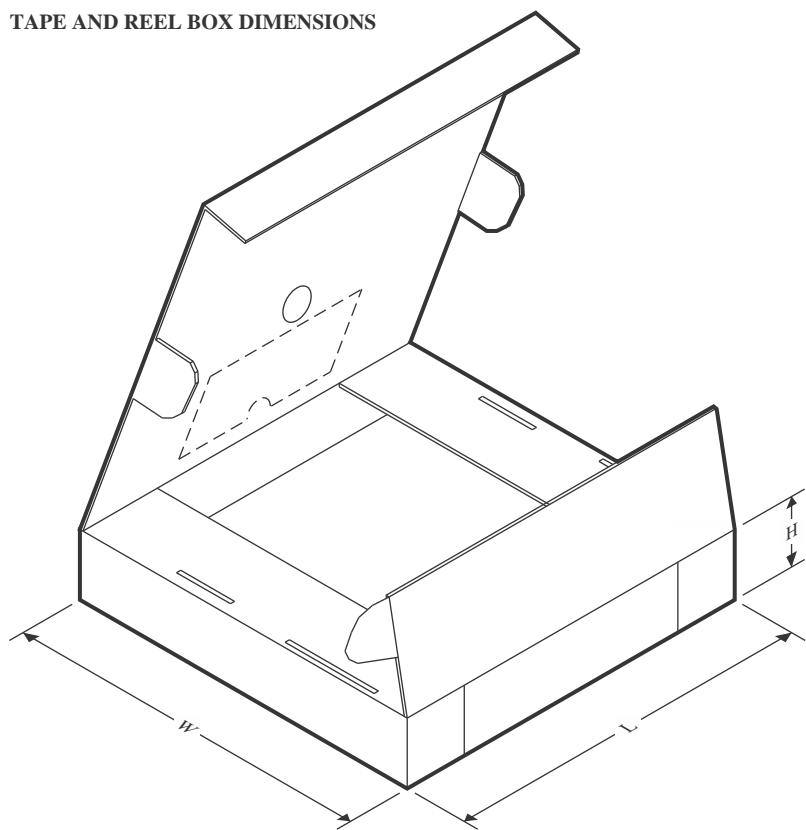
A0	Dimension designed to accommodate the component width
B0	Dimension designed to accommodate the component length
K0	Dimension designed to accommodate the component thickness
W	Overall width of the carrier tape
P1	Pitch between successive cavity centers

### QUADRANT ASSIGNMENTS FOR PIN 1 ORIENTATION IN TAPE



\*All dimensions are nominal

Device	Package Type	Package Drawing	Pins	SPQ	Reel Diameter (mm)	Reel Width W1 (mm)	A0 (mm)	B0 (mm)	K0 (mm)	P1 (mm)	W (mm)	Pin1 Quadrant
CSD17585F5	PICOSTAR	YJK	3	3000	180.0	8.4	0.92	1.68	0.42	4.0	8.0	Q1
CSD17585F5T	PICOSTAR	YJK	3	250	180.0	8.4	0.92	1.68	0.42	4.0	8.0	Q1

**TAPE AND REEL BOX DIMENSIONS**


\*All dimensions are nominal

Device	Package Type	Package Drawing	Pins	SPQ	Length (mm)	Width (mm)	Height (mm)
CSD17585F5	PICOSTAR	YJK	3	3000	182.0	182.0	20.0
CSD17585F5T	PICOSTAR	YJK	3	250	182.0	182.0	20.0

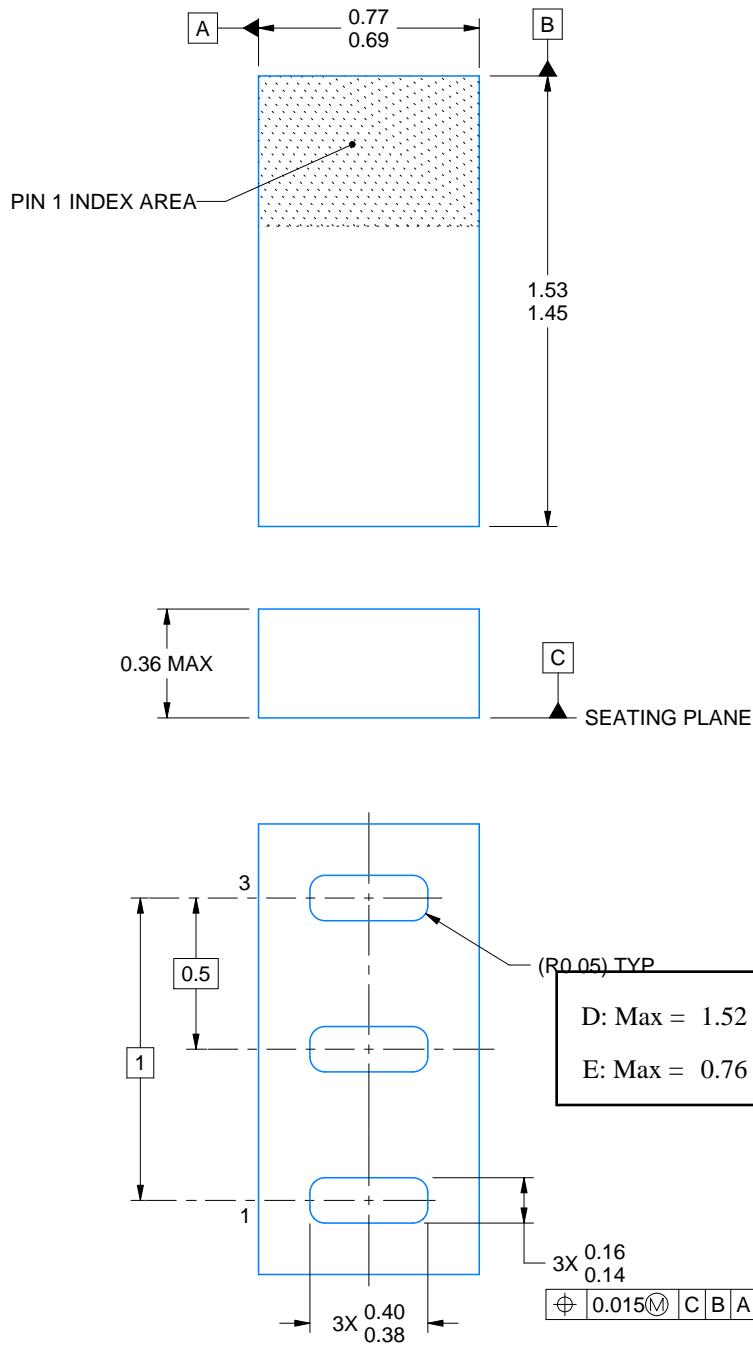
# PACKAGE OUTLINE

**YJK0003A**



**PicoStar™ - 0.36 mm max height**

PicoStar™



4222132/C 03/2022

PicoStar is a trademark of Texas Instruments.

NOTES:

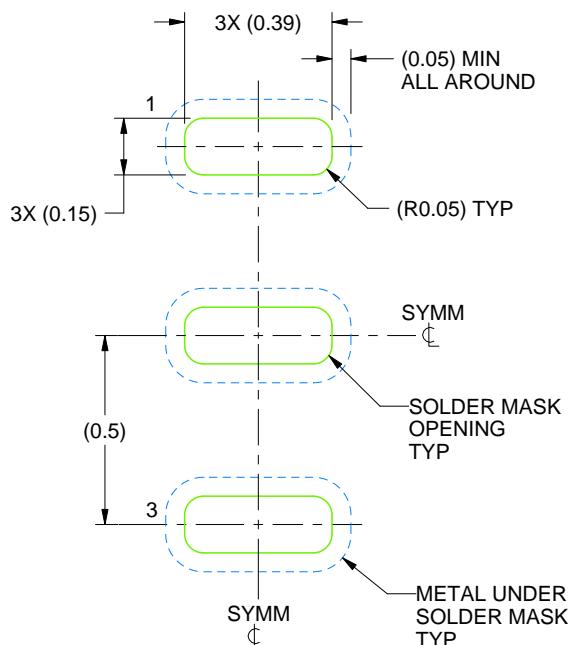
1. All linear dimensions are in millimeters. Any dimensions in parenthesis are for reference only. Dimensioning and tolerancing per ASME Y14.5M
2. This drawing is subject to change without notice.
3. This package is a Pb-free bump design. Bump finish may vary. To determine the exact finish, refer to the device datasheet or contact a local TI representative.

# EXAMPLE BOARD LAYOUT

**YJK0003A**

**PicoStar™ - 0.36 mm max height**

PicoStar™



**LAND PATTERN EXAMPLE**  
SOLDER MASK DEFINED  
SCALE:50X

4222132/C 03/2022

NOTES: (continued)

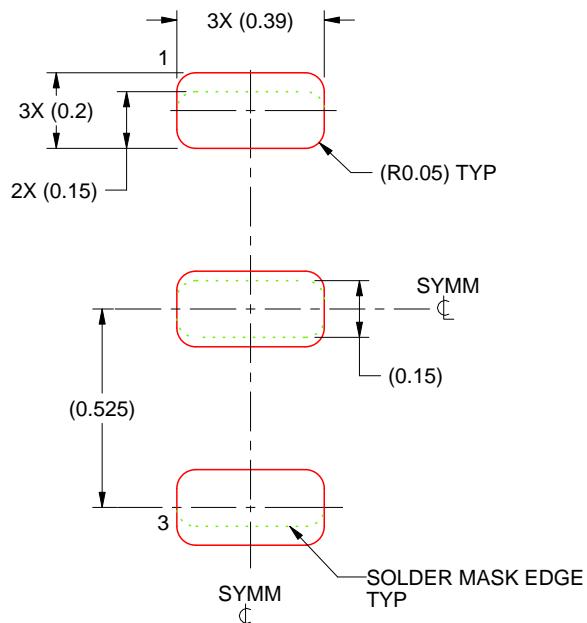
4. For more information, see Texas Instruments literature number SLUA271 ([www.ti.com/lit/slua271](http://www.ti.com/lit/slua271)).

# EXAMPLE STENCIL DESIGN

**YJK0003A**

**PicoStar™ - 0.36 mm max height**

PicoStar™



**SOLDER PASTE EXAMPLE**  
BASED ON 0.075 - 0.1 mm THICK STENCIL  
SCALE:50X

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NOTES: (continued)

5. Laser cutting apertures with trapezoidal walls and rounded corners may offer better paste release. IPC-7525 may have alternate design recommendations.

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